

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Yusuke Kohyama et al.

Atty. Docket: 1701.00021

Serial No.: Rule 1.53(b) Divisional of 08/720,032

Art Unit: 2835

Filed: Herewith

Examiner: H. Duong

For: **STACKED CAPACITOR-TYPE SEMICONDUCTOR
STORAGE DEVICE AND MANUFACTURING
METHOD THEREOF**

PRELIMINARY AMENDMENT

Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

Prior to examination on the merits and in conjunction with the divisional application filed herewith pursuant to 37 C.F.R. § 1.53(b), please amend the above-identified application as follows:

IN THE SPECIFICATION:

Please amend the specification as follows:

Page 1, before line 1, insert This application is a divisional of prior application serial no.

now U.S. Pat. No. 6,130,450
08/720,032 filed September 27, 1996--.

Page 1, line 12, before "DRAM" insert --a--;

line 26, delete "there suggests" and after "cell" insert --is suggested as--.

Page 2, line 12, change "an" to --a--.

Page 3, line 14, change "an" to --a--.

Page 4, line 10, change "yielding" to --yield--;

line 20, change "excellent yielding" to --an excellent yield--;

line 25, change "comprising" to --comprises--.

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m. f. r. d. g. n.